# XL1010-BD



### Low Noise Amplifier 20.0-38.0 GHz

Mimix Broadband

#### **Features**

- 17.0 dB Small Signal Gain
- 3.0 dB Noise Figure
- Single, Positive Bias Supply
- 100% On-Wafer RF Testing
- RoHS\* Compliant and 260°C Reflow Compatible

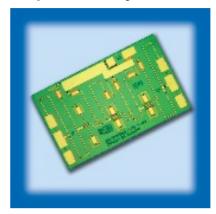
### **Description**

M/A-COM Tech's three stage 20.0-38.0 GHz GaAs MMIC low noise amplifier has a small signal gain of 17.0 dB with a noise figure of 3.0 dB. The device uses M/A-COM Tech's GaAs PHEMT device model technology, and is based upon electron beam lithography to ensure high repeatability and uniformity. The device is well suited to multiple receiver applications which require broadband performance with simple bias requirements.

#### **Ordering Information**

Part Number	Package			
XL1010-BD-000X	Where "X" is RoHS compli- ant die packed in "V" – vac- uum released gel paks or "W" – waffle trays			
XL1010-BD-EV1	evaluation module			

#### **Chip Device Layout**



### **Absolute Maximum Ratings**

Parameter	Absolute Max.		
Supply Voltage (Vd)	+7.0 VDC		
Supply Current (Id1,2,3)	70 mA		
Input Power (Pin)	+12.0 dBm		
Storage Temperature (Tstg)	-65 to +165 °C		
Operating Temperature (Ta)	-55 to MTTF Graph <sup>1</sup>		
Channel Temperature (Tch)	MTTF Graph <sup>1</sup>		

Channel temperature directly affects a device's MTTF. It is recommended to keep channel temperature as low as possible to maximize

## Electrical Specifications: 20-38 GHz (Ambient Temperature T = 25°C)

Parameter	Units	Min.	Тур.	Max.
Input Return Loss (S11)	dB	-	12.0	-
Output Return Loss (S22)	dB	-	15.0	-
Small Signal Gain (S21)	dB	-	17.0	-
Gain Flatness (∆S21)	dB	-	+/-2.0	-
Reverse Isolation (S12)	dB	-	45.0	-
Noise Figure (NF)	dB	-	3.0	-
Output Power for 1dB Compression (P1dB)	dBm	-	TBD	-
Drain Bias Voltage (Vd)	VDC	3.0	4.0	5.0
Supply Current (Id)	mA	-	45	60

<sup>•</sup> North America Tel: 800.366.2266 • Europe Tel: +353.21.244.6400 • China Tel: +86.21.2407.1588 • India Tel: +91.80.43537383 Visit www.macomtech.com for additional data sheets and product information.

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### **Handling Procedures**

Please observe the following precautions to avoid damage:

### **Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these class 2 devices.

typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available.

Commitment to produce in volume is not guaranteed.